NSN 5961-01-077-2946

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View Online at https://aerobasegroup.com/nsn/5961-01-077-2946 **Inclosure Material:** Metal **Overall Length:** 0.188 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.220 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -49.0 gate to source voltage and 40.0 drain to source voltage and 30.0 drain to gate voltage **Current Rating Per Characteristic:** 50.00 milliamperes gate current **Power Rating Per Characteristic:** 0.4 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L02709; for navy nuclear propulsion plant products only **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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